

## 10G Symmetrical EPON ONU Transceiver

### PRODUCT FEATURES

IEEE802.3av Gigabit Ethernet compliant

SFP+ package with SC Receptacle

1270nm DFB Burst Mode 10.3125Gbps transmit

Continuous Mode 10.3125Gbps Receiver

Single +3.3V power supply

SFP+ MSA SFF-8431 compliant

Digital Diagnostic SFF-8472 compliant

Case operation temperature:0~70 °C

LVTTL Bias Control input and Rx Signal Detect output

Laser Class 1 Product which comply with the  
Requirements of IEC 60825-1 and IEC 60825-2



### APPLICATIONS

IEEE 802.3av 10GBASE-PR30

Burst Mode Application

FTTx WDM Broadband Access

### PRODUCT DESCRIPTION

HC's 10G EPON ONU transceiver EX-U1211-30D is designed for Gigabit Ethernet Passive Optical

Network transmission. The module is contained in a SFP+ package with SC/UPC receptacle connector. The module consists 1270nm DFB laser, APD+TIA, Preamplifier and WDM filter in a high-integrated optical sub-assembly, and it receives up to 10.3125Gbps of continuous data at 1577nm, and transmits 10.3125Gbps of burst-mode data at 1270nm.

### I. Absolute Maximum Ratings

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Storage Temperature	Ts	-40		85	°C	
Storage Ambient Humidity	HA	5		95	%	
Power Supply Voltage	VCC	-0.3		4	V	
Signal Input Voltage		-0.3		Vcc+0.3	V	
Receiver Damage Threshold		5			dBm	

### II. Recommended Operating Conditions

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note	
Case Operating Temperature	Tcase	0		70	°C		
Ambient Humidity	HA	5		95	%	Non-condensing	
Power Supply Voltage	VCC	3.13	3.3	3.47	V		
Power Supply Current	ICC			660	mA		
Power Supply Noise Rejection				100	mVp-p	100Hz to 1MHz	
Data Rate	DR	10.3125-100ppm	10.3125	10.3125+100ppm	Gbps		
Coupled fiber		Single mode fiber					9/125um SMF

### III. Specification of Transmitter

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Average Launched Power	PO	4		9	dBm	Note (1)
Extinction Ratio	ER	6			dB	
Center Wavelength	$\lambda_C$	1260		1280	nm	DFB Laser
Spectrum Width (-20dB)	$\sigma$			1	nm	
Side Mode Suppression Ratio	SMSR	30			nm	
Transmitter OFF Output Power	POff			-45	dBm	
Total Jitter	tJ			0.35	UI	Note (2)
Optical Return Loss Tolerance	ORLT			15	dB	

Relative Intensity Noise	RIN15OMA			-128	dB/Hz	
Optical Transmitter Reflectance				-10	dB	
Output Eye Mask	Compliant with IEEE 802.3av					Note (3)

Note (1). Launched power (avg.) is power coupled into  
a single mode fiber with master connector.( Before of Life ) Note (2).  
Measure at 2<sup>31</sup>-1 NRZ PRBS pattern  
Note (3). Transmitter eye mask definition

#### IV. Specification of Receiver

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Input Optical Wavelength	$\lambda_{IN}$	1575	1577	1580	nm	
Receiver Sensitivity	Psen1			-24.5	dBm	Note (1)
	Psen2			-28.5	dBm	
Input Saturation Power (Overload)	P <sub>SAT</sub>	-8			dBm	
Los Of Signal Assert	PA			-30	dBm	
Los Of Signal De-assert	PD	-38			dBm	Note (2)
LOS Hysteresis	PA-PD	0.5	2	6	dB	
Receiver Reflectance	1580 to 1600nm			-12	dB	Note (3)
Optical Isolation from External Source	1260 to 1360nm			-43	dB	

Note (1). Psen1 measured with Light source 1577nm, ER=9dB; BER = $\leq 10^{-10}$ @PRBS=2<sup>31</sup> NRZ Psen2  
measured with Light source 1577nm, ER=9dB; BER = $\leq 10^{-3}$ @PRBS=2<sup>31</sup> NRZ

Note (2). When LOS de-asserted, the RX data+/- output is High-level (fixed) Note (3).

Measured at wavelength of 1577nm.

#### V. Electrical Interface Characteristics

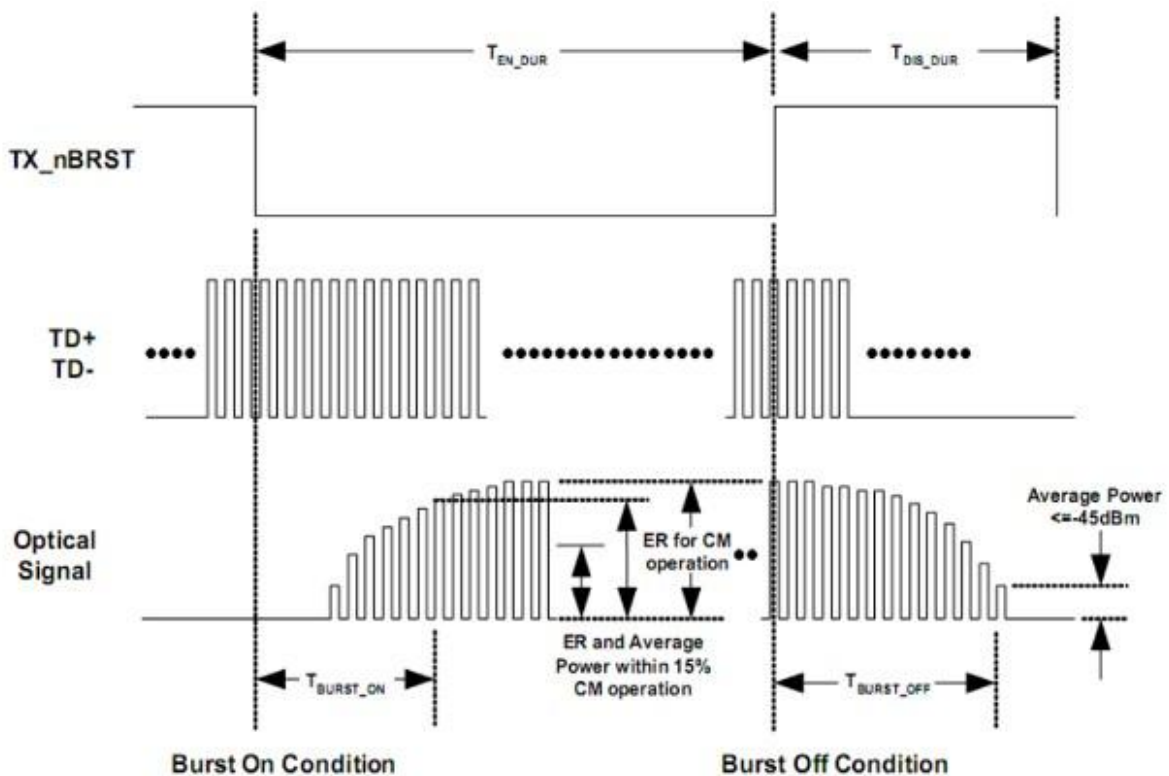
Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
<b>Transmitter</b>						
Differential line input Impedance	RIN	90	100	110	Ohm	
Differential Data Input Swing	VDT	200		1600	mVp-p	Note (1)
BiasCNT(n) Input Voltage- High	VBCH	2		V <sub>cc</sub> +0.3	V	LVTTTL
BiasCNT(n) Input Voltage- Low	VBCL	0		0.8	V	
<b>Receiver</b>						
Differential Data Output Swing	VDR	500		1000	mVp-p	Note (1)

Signal Detect Output Voltage-High	VLOSH	2		V <sub>cc</sub> +0.3	V	LVTTTL
Signal Detect Output Voltage-Low	VLOSL	0		0.8	V	

Note (1). Internally AC coupled.

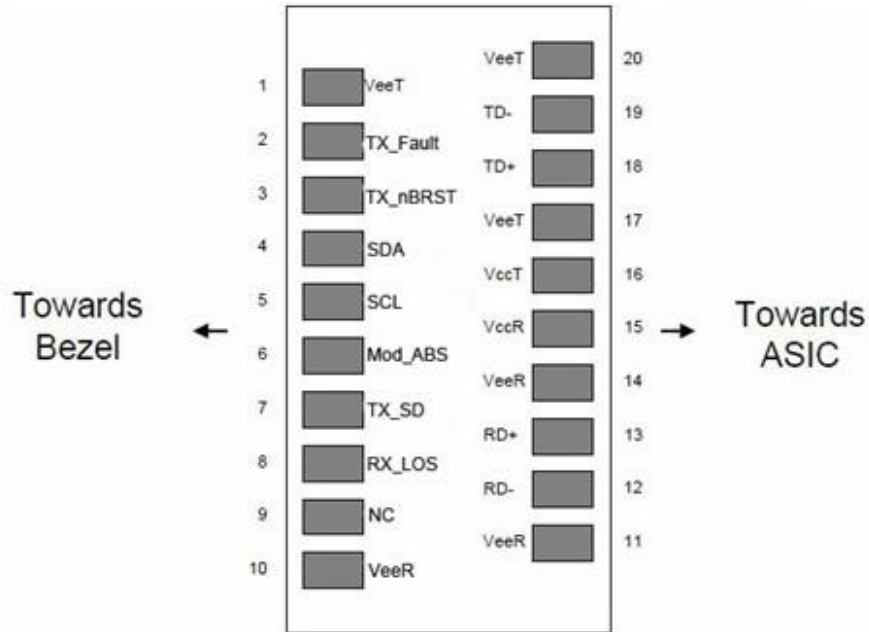
**VI. Transmitter Burst Mode Timing Characteristics ( BEN=low level )**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Burst Enable Duration	T <sub>EN_DUR</sub>	1000			ns	
Burst Disable Duration	T <sub>DIS_DUR</sub>	112		1000000	ns	
Burst Turn On Time	T <sub>BURST_ON</sub>			512	ns	
Burst Turn Off Time	T <sub>BURST_off</sub>			512	ns	



**Figure1: Timing Parameter Definition In Burst Mode Sequence**

## VII. Pin Description



Pin	Symbol	Name/Description	Ref.
1	VeeT	Transmitter Ground	1
2	TX_Fault	Transmitter Fault.	
3	TX_nBRST	Transmitter Burst Control	
4	SDA	2 wire Serial Interface Data Line(MOD_DEF2)	2
5	SCL	2 wire Serial Interface Clock(MOD_DEF1)	
6	Mod_ABS	Module Absent, Connect to VeeT or VeeR in the module(MOD_DEF0)	
7	TX_SD	TX signal Detect	3
8	RX_LOS	Loss of Signal indication.	4
9	NC	Not Connected	
10	VeeR	Receiver Ground	1
11	VeeR	Receiver Ground	1
12	RD-	Receiver Inverted DATA out. AC Coupled	
13	RD+	Receiver Non-inverted DATA out. AC Coupled	
14	Vee	Receiver Ground	1
15	VccR	Receiver Power Supply	
16	VccT	Transmitter Power Supply	
17	VeeT	Transmitter Ground	1
18	TD+	Transmitter Non-Inverted DATA in. AC Coupled.	
19	TD-	Transmitter Inverted DATA in. AC Coupled.	

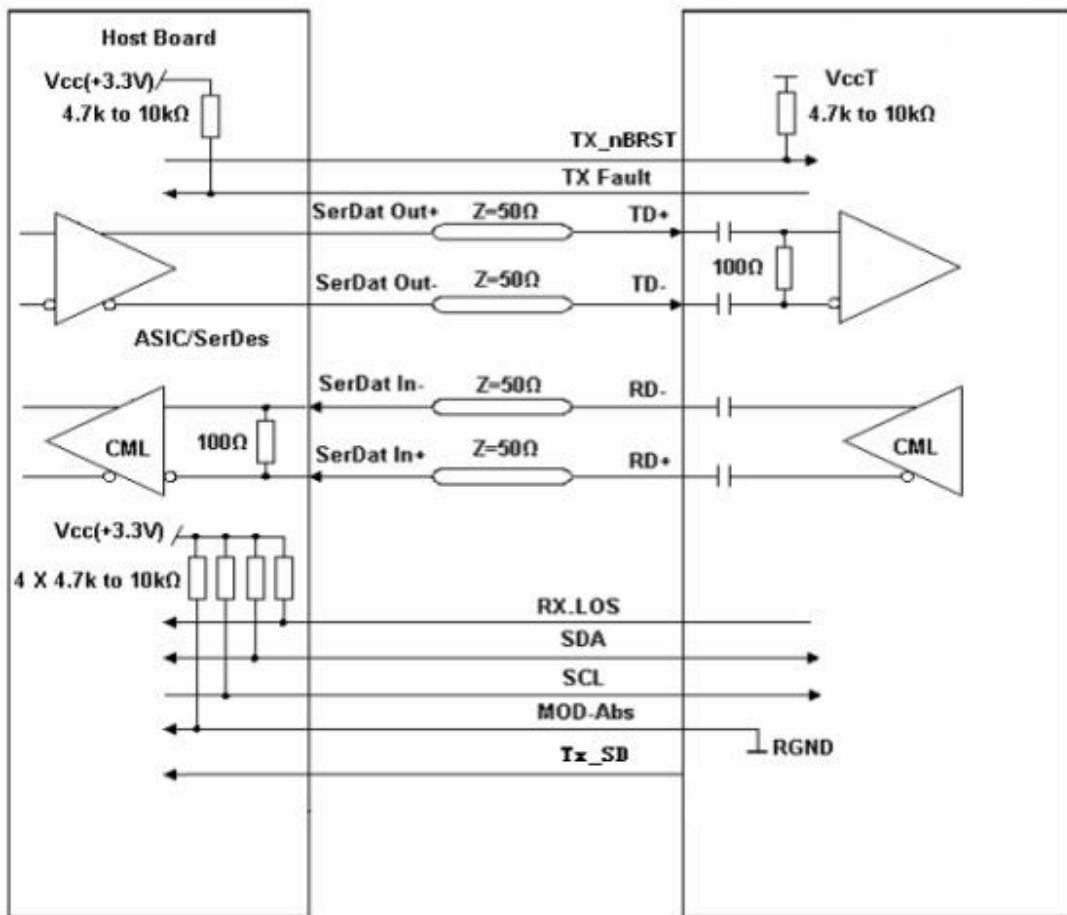
20	VccT	Transmitter Ground	1
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**Notes:**

1. Circuit ground is internally isolated from chassis ground.
2. SDA is open collector output. Should be pulled up with 4.7k - 10kohms to VccT in the module.
3. TX signal Detect, TX Active State:High.

LOS is open collector output. Should be pulled up with 4.7k - 10kohms on host board to a voltage between 2.0V and 3.6V. Logic 0 indicates normal operation; logic 1 indicates loss of signal.

**VIII. Recommended Interface Circuit**



**Figure2: Recommended Interface Circuit**

## IX. Outline Dimensions

Parameter	Unit	Description	Note
Mechanical Dimensions	mm	68.8 x 13.4 x 8.5	
Connector Type	-	SC/UPC connector	IEC-61754-4

